ACS712

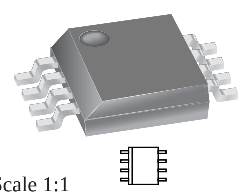
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with 2.1 kVRMS Isolation and a Low-Resistance Current Conductor

Features and Benefits

- Low-noise analog signal path
- Device bandwidth is set via the new FILTER pin
- 5 µs output rise time in response to step input current
- 80 kHz bandwidth
- Total output error 1.5% at $T_A = 25°C$
- Small footprint, low-profile SOIC8 package
- 1.2 mΩ internal conductor resistance
- 2.1 kVRMS minimum isolation voltage from pins 1-4 to pins 5-8
- 5.0 V, single supply operation
- 66 to 185 mV/A output sensitivity
- Output voltage proportional to AC or DC currents
- Factory-trimmed for accuracy
- Extremely stable output offset voltage
- Nearly zero magnetic hysteresis
- Ratiometric output from supply voltage

TÜV America
Certificate Number:
U8V 06 05 54214 010

Package: 8 Lead SOIC (suffix LC)



Approximate Scale 1:1

Description

The Allegro™ ACS712 provides economical and precise solutions for AC or DC current sensing in industrial, commercial, and communications systems. The device package allows for easy implementation by the customer. Typical applications include motor control, load detection and management, switch-mode power supplies, and overcurrent fault protection. The device is not intended for automotive applications.

The device consists of a precise, low-offset, linear Hall circuit with a copper conduction path located near the surface of the die. Applied current flowing through this copper conduction path generates a magnetic field which the Hall IC converts into a proportional voltage. Device accuracy is optimized through the close proximity of the magnetic signal to the Hall transducer. A precise, proportional voltage is provided by the low-offset, chopper-stabilized BiCMOS Hall IC, which is programmed for accuracy after packaging.

The output of the device has a positive slope ($>V_{IOUT(Q)}$) when an increasing current flows through the primary copper conduction path (from pins 1 and 2, to pins 3 and 4), which is the path used for current sampling. The internal resistance of this conductive path is 1.2 mΩ typical, providing low power loss. The thickness of the copper conductor allows survival of

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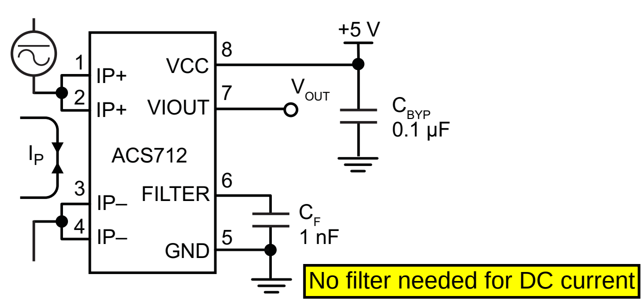
Typical Application



Application 1. The ACS712 outputs an analog signal, V_{OUT}. that varies linearly with the uni- or bi-directional AC or DC primary sampled current, I_P, within the range specified. C_F is recommended for noise management, with values that depend on the application.

Description (continued)

the device at up to 5× overcurrent conditions. The terminals of the conductive path are electrically isolated from the signal leads (pins 5 through 8). This allows the ACS712 to be used in applications requiring electrical isolation without the use of opto-isolators or other costly isolation techniques.

The ACS712 is provided in a small, surface mount SOIC8 package. The leadframe is plated with 100% matte tin, which is compatible with standard lead (Pb) free printed circuit board assembly processes. Internally, the device is Pb-free, except for flip-chip high-temperature Pb-based solder balls, currently exempt from RoHS. The device is fully calibrated prior to shipment from the factory.

Selection Guide

Part Number	Packing*	T_A (°C)	Optimized Range, I_P (A)	Sensitivity, Sens (Typ) (mV/A)
ACS712ELCTR-05B-T	Tape and reel, 3000 pieces/reel	–40 to 85	±5	185
ACS712ELCTR-20A-T	Tape and reel, 3000 pieces/reel	–40 to 85	±20	100
ACS712ELCTR-30A-T	Tape and reel, 3000 pieces/reel	–40 to 85	±30	66

*Contact Allegro for additional packing options.

Absolute Maximum Ratings

Characteristic	Symbol	Notes	Rating	Units
Supply Voltage	V_{CC}		8	V
Reverse Supply Voltage	V_{RCC}		–0.1	V
Output Voltage	V_{IOUT}		8	V
Reverse Output Voltage	V_{RIOUT}		–0.1	V
Output Current Source	$I_{IOUT(Source)}$		3	mA
Output Current Sink	$I_{IOUT(Sink)}$		10	mA
Overcurrent Transient Tolerance	I_P	1 pulse, 100 ms	100	A
Nominal Operating Ambient Temperature	T_A	Range E	–40 to 85	ºC
Maximum Junction Temperature	T_J(max)		165	ºC
Storage Temperature	T_{stg}		–65 to 170	ºC

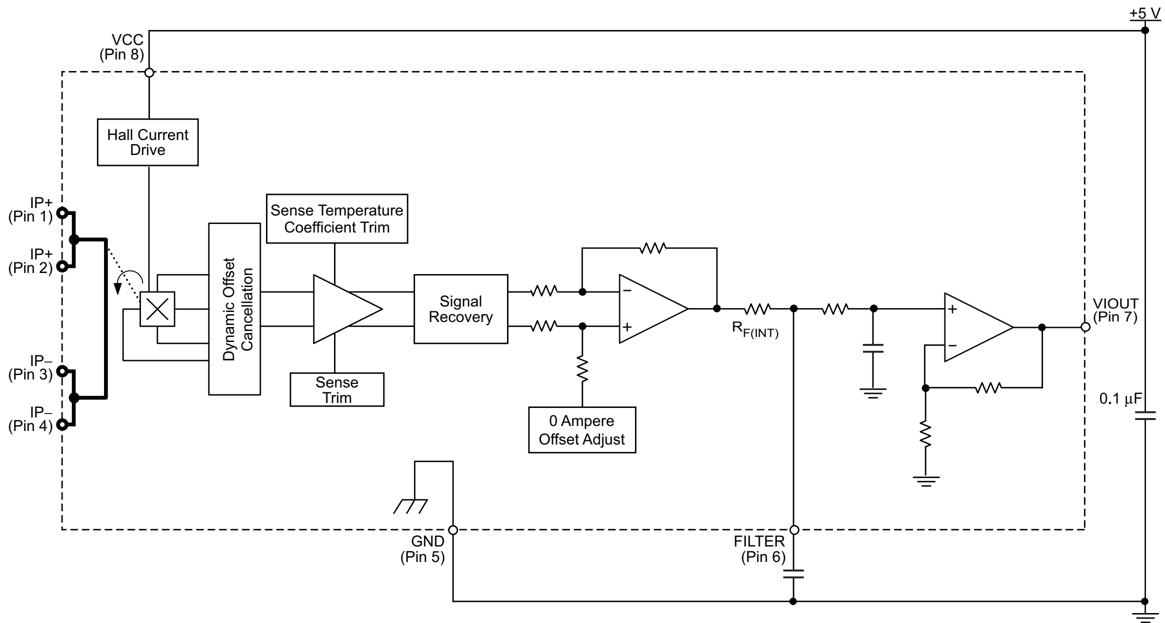
Isolation Characteristics

Characteristic	Symbol	Notes	Rating	Unit
Dielectric Strength Test Voltage*	V_{ISO}	Agency type-tested for 60 seconds per UL standard 60950-1, 1st Edition	2100	VAC
Working Voltage for Basic Isolation	V_{WFSI}	For basic (single) isolation per UL standard 60950-1, 1st Edition	354	VDC or V_{pk}
Working Voltage for Reinforced Isolation	V_{WFRI}	For reinforced (double) isolation per UL standard 60950-1, 1st Edition	184	VDC or V_{pk}

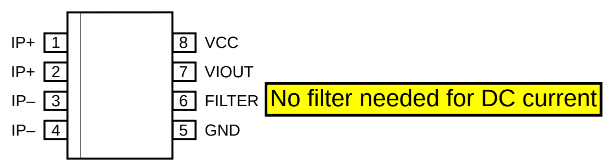
* Allegro does not conduct 60-second testing. It is done only during the UL certification process.

Parameter	Specification
Fire and Electric Shock	CAN/CSA-C22.2 No. 60950-1-03 UL 60950-1:2003 EN 60950-1:2001

Functional Block Diagram



Pin-out Diagram



Terminal List Table

Number	Name	Description
1 and 2	IP+	Terminals for current being sampled; fused internally
3 and 4	IP–	Terminals for current being sampled; fused internally
5	GND	Signal ground terminal
6	FILTER	Terminal for external capacitor that sets bandwidth
7	VIOUT	Analog output signal
8	VCC	Device power supply terminal

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COMMON OPERATING CHARACTERISTICS[1] over full range of T_A, C_F = 1 nF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
ELECTRICAL CHARACTERISTICS						
Supply Voltage	V_{CC}		4.5	5.0	5.5	V
Supply Current	I_{CC}	V_{CC} = 5.0 V, output open	–	10	13	mA
Output Capacitance Load	C_{LOAD}	VIOUT to GND	–	–	10	nF
Output Resistive Load	R_{LOAD}	VIOUT to GND	4.7	–	–	kΩ
Primary Conductor Resistance	$R_{PRIMARY}$	T_A = 25°C	–	1.2	–	mΩ
Rise Time	t_r	$I_P = I_P(max)$, T_A = 25°C, C_{OUT} = open	–	3.5	–	μs
Frequency Bandwidth	f	–3 dB, T_A = 25°C; I_P is 10 A peak-to-peak	–	80	–	kHz
Nonlinearity	E_{LIN}	Over full range of I_P	–	1.5	–	%
Symmetry	E_{SYM}	Over full range of I_P	98	100	102	%
Zero Current Output Voltage	$V_{IOUT(Q)}$	Bidirectional; I_P = 0 A, T_A = 25°C	–	V_{CC} × 0.5	–	V
Power-On Time	t_{PO}	Output reaches 90% of steady-state level, T_J = 25°C, 20 A present on leadframe	–	35	–	μs
Magnetic Coupling[2]			–	12	–	G/A
Internal Filter Resistance[3]	$R_{F(INT)}$			1.7		kΩ

[1]Device may be operated at higher primary current levels, I_P, and ambient, T_A, and internal leadframe temperatures, T_A, provided that the Maximum Junction Temperature, T_J(max), is not exceeded.

[2]1G = 0.1 mT.

[3]$R_{F(INT)}$ forms an RC circuit via the FILTER pin.

COMMON THERMAL CHARACTERISTICS[1]

			Min.	Typ.	Max.	Units
Operating Internal Leadframe Temperature	T_A	E range	–40	–	85	°C
					Value	Units
Junction-to-Lead Thermal Resistance[2]	$R_{\theta JL}$	Mounted on the Allegro ASEK 712 evaluation board			5	°C/W
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	Mounted on the Allegro 85-0322 evaluation board, includes the power consumed by the board			23	°C/W

[1]Additional thermal information is available on the Allegro website.

[2]The Allegro evaluation board has 1500 mm^2 of 2 oz. copper on each side, connected to pins 1 and 2, and to pins 3 and 4, with thermal vias connecting the layers. Performance values include the power consumed by the PCB. Further details on the board are available from the Frequently Asked Questions document on our website. Further information about board design and thermal performance also can be found in the Applications Information section of this datasheet.

x05B PERFORMANCE CHARACTERISTICS[1] T_A = –40°C to 85°C, C_F = 1 nF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Optimized Accuracy Range	I_P		–5	–	5	A
Sensitivity	Sens	Over full range of I_P, T_A = 25°C	180	185	190	mV/A
Noise	$V_{NOISE(PP)}$	Peak-to-peak, T_A = 25°C, 185 mV/A programmed Sensitivity, C_F = 47 nF, C_{OUT} = open, 2 kHz bandwidth	–	21	–	mV
Zero Current Output Slope	$\Delta V_{OUT(Q)}$	T_A = –40°C to 25°C	–	–0.26	–	mV/°C
		T_A = 25°C to 150°C	–	–0.08	–	mV/°C
Sensitivity Slope	ΔSens	T_A = –40°C to 25°C	–	0.054	–	mV/A/°C
		T_A = 25°C to 150°C	–	–0.008	–	mV/A/°C
Total Output Error[2]	E_{TOT}	I_P =±5 A, T_A = 25°C	–	±1.5	–	%

[1]Device may be operated at higher primary current levels, I_P, and ambient temperatures, T_A, provided that the Maximum Junction Temperature, $T_{J(max)}$, is not exceeded.

[2]Percentage of I_P, with I_P = 5 A. Output filtered.

x20A PERFORMANCE CHARACTERISTICS[1] T_A = –40°C to 85°C, C_F = 1 nF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Optimized Accuracy Range	I_P		–20	–	20	A
Sensitivity	Sens	Over full range of I_P, T_A = 25°C	96	100	104	mV/A
Noise	$V_{NOISE(PP)}$	Peak-to-peak, T_A = 25°C, 100 mV/A programmed Sensitivity, C_F = 47 nF, C_{OUT} = open, 2 kHz bandwidth	–	11	–	mV
Zero Current Output Slope	$\Delta V_{OUT(Q)}$	T_A = –40°C to 25°C	–	–0.34	–	mV/°C
		T_A = 25°C to 150°C	–	–0.07	–	mV/°C
Sensitivity Slope	ΔSens	T_A = –40°C to 25°C	–	0.017	–	mV/A/°C
		T_A = 25°C to 150°C	–	–0.004	–	mV/A/°C
Total Output Error[2]	E_{TOT}	I_P =±20 A, T_A = 25°C	–	±1.5	–	%

[1]Device may be operated at higher primary current levels, I_P, and ambient temperatures, T_A, provided that the Maximum Junction Temperature, T_J(max), is not exceeded.

[2]Percentage of I_P, with I_P = 20 A. Output filtered.

x30A PERFORMANCE CHARACTERISTICS[1] T_A = –40°C to 85°C, C_F = 1 nF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Optimized Accuracy Range	I_P		–30	–	30	A
Sensitivity	Sens	Over full range of I_P, T_A = 25°C	63	66	69	mV/A
Noise	$V_{NOISE(PP)}$	Peak-to-peak, T_A = 25°C, 66 mV/A programmed Sensitivity, C_F = 47 nF, C_{OUT} = open, 2 kHz bandwidth	–	7	–	mV
Zero Current Output Slope	$\Delta V_{OUT(Q)}$	T_A = –40°C to 25°C	–	–0.35	–	mV/°C
		T_A = 25°C to 150°C	–	–0.08	–	mV/°C
Sensitivity Slope	ΔSens	T_A = –40°C to 25°C	–	0.007	–	mV/A/°C
		T_A = 25°C to 150°C	–	–0.002	–	mV/A/°C
Total Output Error[2]	E_{TOT}	I_P = ±30 A, T_A = 25°C	–	±1.5	–	%

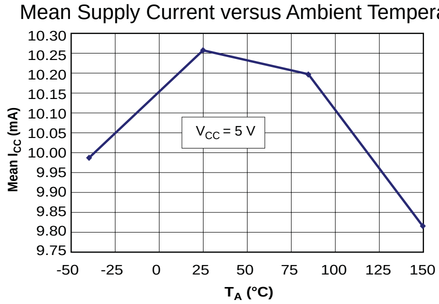
[1]Device may be operated at higher primary current levels, I_P, and ambient temperatures, T_A, provided that the Maximum Junction Temperature, T_J(max), is not exceeded.

[2]Percentage of I_P, with I_P = 30 A. Output filtered.

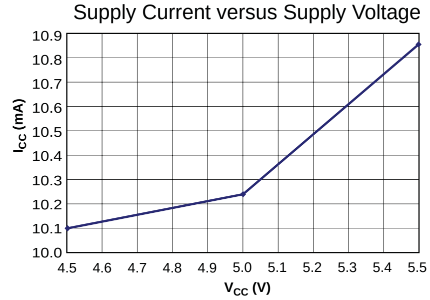
Characteristic Performance

I_P = 5 A, unless otherwise specified

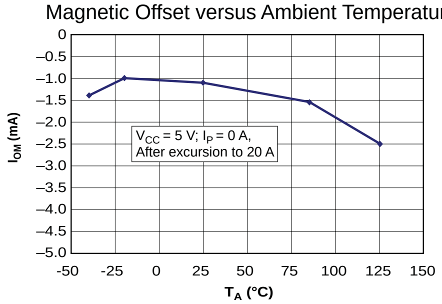
Mean Supply Current versus Ambient Temperature



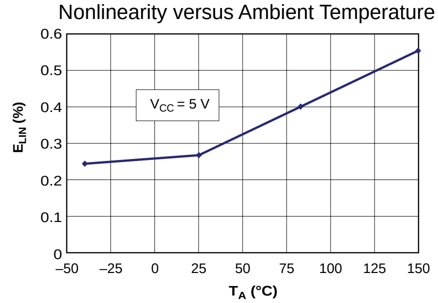
Supply Current versus Supply Voltage



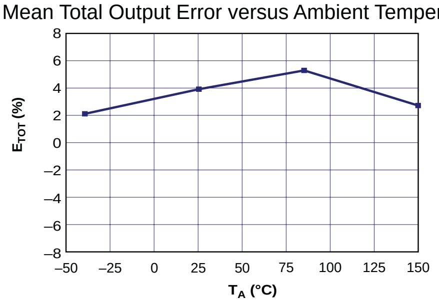
Magnetic Offset versus Ambient Temperature



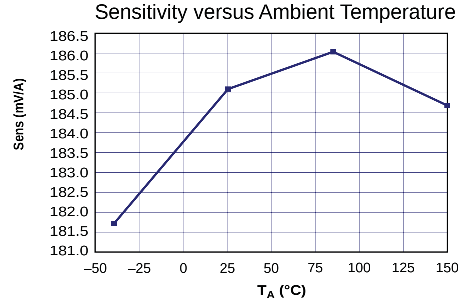
Nonlinearity versus Ambient Temperature



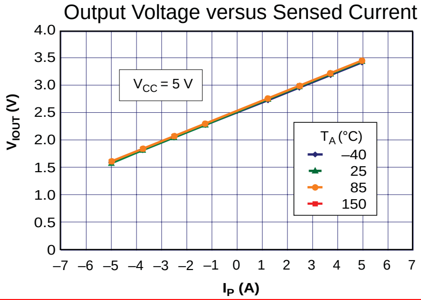
Mean Total Output Error versus Ambient Temperature



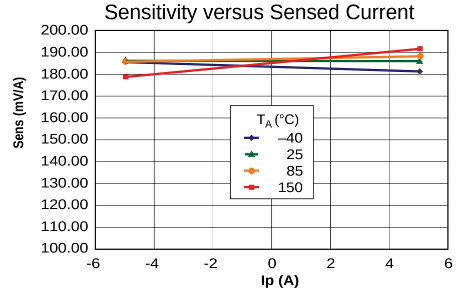
Sensitivity versus Ambient Temperature



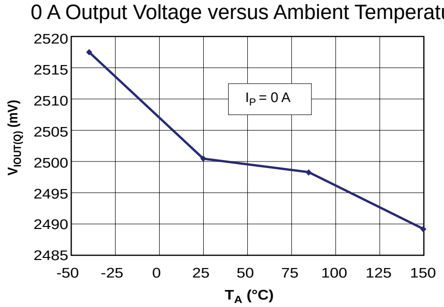
Output Voltage versus Sensed Current



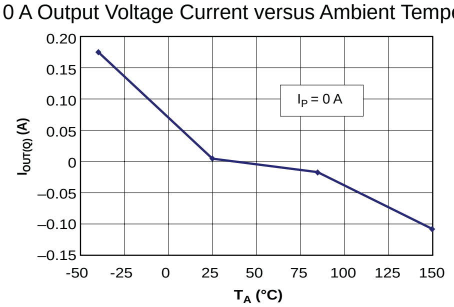
Sensitivity versus Sensed Current



0 A Output Voltage versus Ambient Temperature



0 A Output Voltage Current versus Ambient Temperature



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Definitions of Accuracy Characteristics

Sensitivity (Sens). The change in device output in response to a 1 A change through the primary conductor. The sensitivity is the product of the magnetic circuit sensitivity (G/A) and the linear IC amplifier gain (mV/G). The linear IC amplifier gain is programmed at the factory to optimize the sensitivity (mV/A) for the full-scale current of the device.

Noise (V_{NOISE}). The product of the linear IC amplifier gain (mV/G) and the noise floor for the Allegro Hall effect linear IC (≈1 G). The noise floor is derived from the thermal and shot noise observed in Hall elements. Dividing the noise (mV) by the sensitivity (mV/A) provides the smallest current that the device is able to resolve.

Linearity (E_{LIN}). The degree to which the voltage output from the IC varies in direct proportion to the primary current through its full-scale amplitude. Nonlinearity in the output can be attributed to the saturation of the flux concentrator approaching the full-scale current. The following equation is used to derive the linearity:

$$100\left\{1-\left[\frac{\Delta\text{ gain}\times\%\text{ sat }(V_{IOUT\_full\text{-}scale\ amperes}-V_{IOUT(Q)})}{2\,(V_{IOUT\_half\text{-}scale\ amperes}-V_{IOUT(Q)})}\right]\right\}$$

where $V_{IOUT\_full\text{-}scale\ amperes}$ = the output voltage (V) when the sampled current approximates full-scale $\pm I_P$.

Symmetry (E_{SYM}). The degree to which the absolute voltage output from the IC varies in proportion to either a positive or negative full-scale primary current. The following formula is used to derive symmetry:

$$100\left(\frac{V_{IOUT\_+\ full\text{-}scale\ amperes}-V_{IOUT(Q)}}{V_{IOUT(Q)}-V_{IOUT\_-full\text{-}scale\ amperes}}\right)$$

Quiescent output voltage ($V_{IOUT(Q)}$). The output of the device when the primary current is zero. For a unipolar supply voltage, it nominally remains at $V_{CC}/2$. Thus, V_{CC} = 5 V translates into $V_{IOUT(Q)}$ = 2.5 V. Variation in $V_{IOUT(Q)}$ can be attributed to the resolution of the Allegro linear IC quiescent voltage trim and thermal drift.

Electrical offset voltage (V_{OE}). The deviation of the device output from its ideal quiescent value of $V_{CC}/2$ due to nonmagnetic causes. To convert this voltage to amperes, divide by the device sensitivity, Sens.

Accuracy (E_{TOT}). The accuracy represents the maximum deviation of the actual output from its ideal value. This is also known as the total output error. The accuracy is illustrated graphically in the output voltage versus current chart at right.

Accuracy is divided into four areas:

- **0 A at 25°C.** Accuracy at the zero current flow at 25°C, without the effects of temperature.
- **0 A over Δ temperature.** Accuracy at the zero current flow including temperature effects.
- **Full-scale current at 25°C.** Accuracy at the the full-scale current at 25°C, without the effects of temperature.
- **Full-scale current over Δ temperature.** Accuracy at the full-scale current flow including temperature effects.

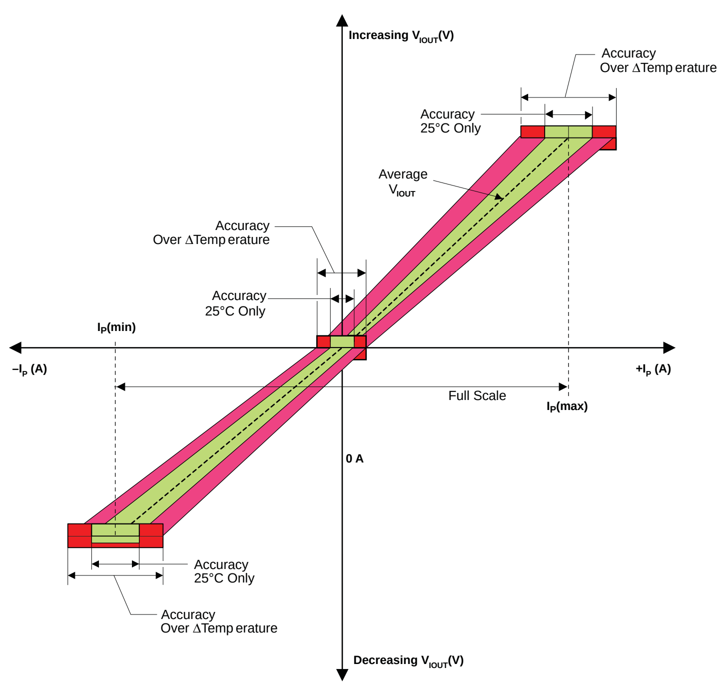
Ratiometry. The ratiometric feature means that its 0 A output, $V_{IOUT(Q)}$, (nominally equal to $V_{CC}/2$) and sensitivity, Sens, are proportional to its supply voltage, V_{CC}. The following formula is used to derive the ratiometric change in 0 A output voltage, $\Delta V_{IOUT(Q)RAT}$ (%).

$$100\left(\frac{V_{IOUT(Q)VCC}\,/\,V_{IOUT(Q)5V}}{V_{CC}\,/\,5\text{ V}}\right)$$

The ratiometric change in sensitivity, $\Delta Sens_{RAT}$ (%), is defined as:

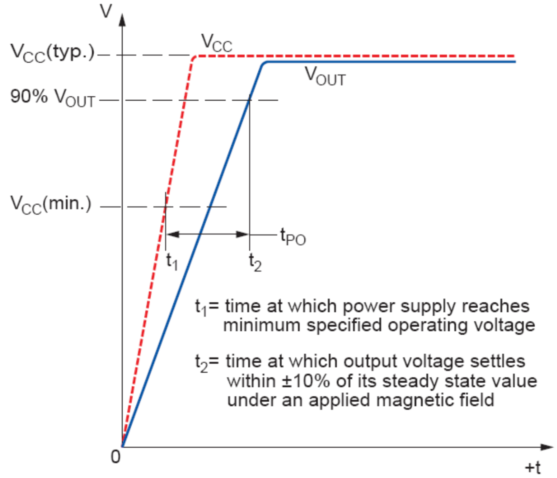
$$100\left(\frac{Sens_{VCC}\,/\,Sens_{5V}}{V_{CC}\,/\,5\text{ V}}\right)$$

Output Voltage versus Sampled Current
Accuracy at 0 A and at Full-Scale Current

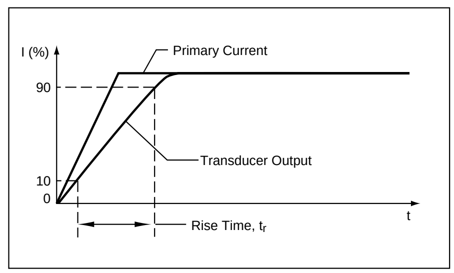


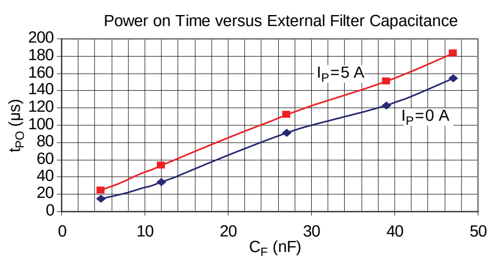
Definitions of Dynamic Response Characteristics

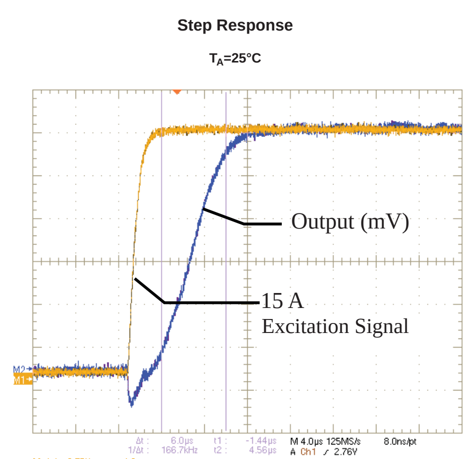
Power-On Time (t_{PO}). When the supply is ramped to its operating voltage, the device requires a finite time to power its internal components before responding to an input magnetic field. Power-On Time, t_{PO} , is defined as the time it takes for the output voltage to settle within ±10% of its steady state value under an applied magnetic field, after the power supply has reached its minimum specified operating voltage, V_{CC}(min), as shown in the chart at right.

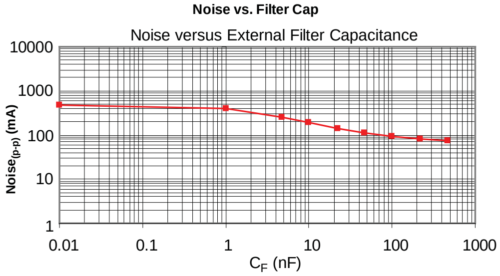


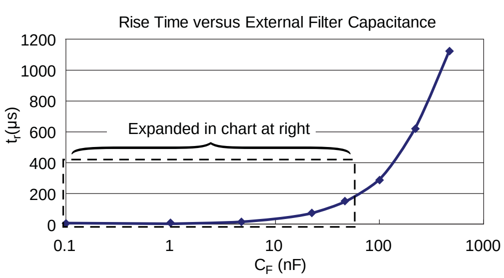
Rise time (t_r). The time interval between a) when the device reaches 10% of its full scale value, and b) when it reaches 90% of its full scale value. The rise time to a step response is used to derive the bandwidth of the device, in which $f(-3\text{ dB}) = 0.35/t_r$. Both t_r and $t_{RESPONSE}$ are detrimentally affected by eddy current losses observed in the conductive IC ground plane.



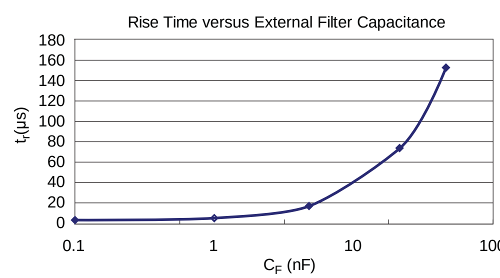




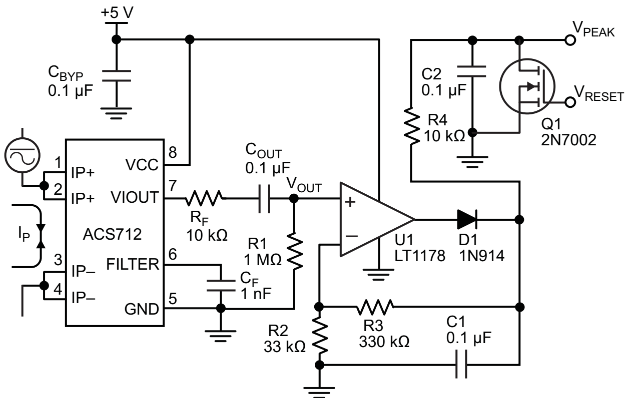




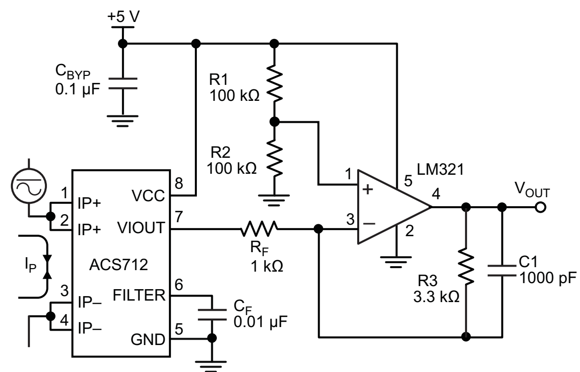
C_F (nF)	t_r (µs)
Open	3.5
1	5.8
4.7	17.5
22	73.5
47	88.2
100	291.3
220	623
470	1120



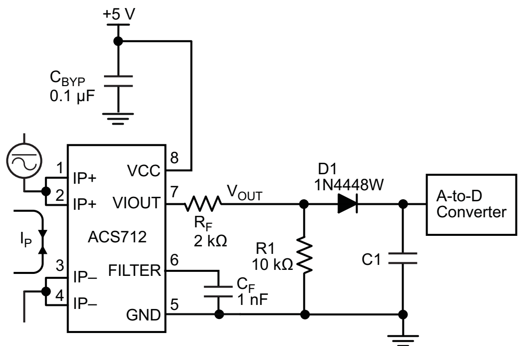
Typical Applications



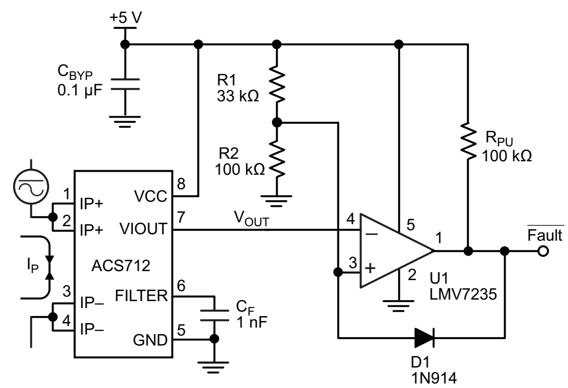
Application 2. Peak Detecting Circuit



Application 3. This configuration increases gain to 610 mV/A (tested using the ACS712ELC-05A).



Application 4. Rectified Output. 3.3 V scaling and rectification application for A-to-D converters. Replaces current transformer solutions with simpler ACS circuit. C1 is a function of the load resistance and filtering desired. R1 can be omitted if the full range is desired.



Application 5. 10 A Overcurrent Fault Latch. Fault threshold set by R1 and R2. This circuit latches an overcurrent fault and holds it until the 5 V rail is powered down.